NSN 5961-01-210-8896

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-210-8896 **Inclosure Material:** Metal **Overall Length:** 0.650 inches **Terminal Length:** 0.750 inches **Overall Diameter:** 1.000 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 44.2 breakdown voltage, dc **Current Rating Per Characteristic:** 5.00 milliamperes forward current, total rms universal **Power Rating Per Characteristic:** 15.0 kilowatts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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